# ATLANTA — micro

#### DC to 8 GHz Gain Block

# **Description**

The AM1064-1 is a high dynamic range DC-coupled amplifier covering up to 8 GHz. The device exhibits a moderate positive gain-slope, providing frequency equalization useful in many broadband applications. With internal  $50\Omega$  matching and packaged in a 3mm QFN or a shielded module, the AM1064-1 represents a compact total PCB footprint.

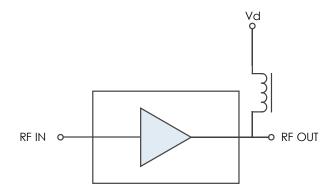




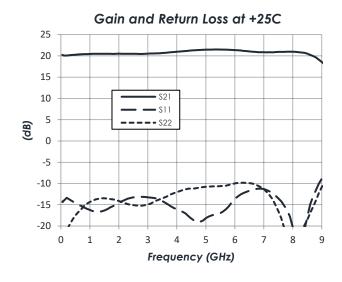
#### **Features**

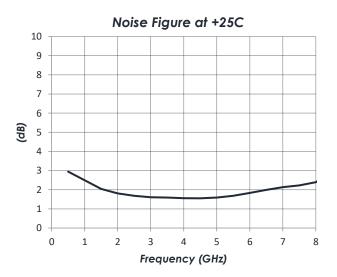
- 21 dB Gain
- 2.0 dB Noise Figure
- +32 dBm OIP3
- +18 dBm P1dB
- +3.3V or +5.0V Operation
- 3mm QFN
- -40C to +85C Operation

# **Functional Diagram**



#### **Characteristic Performance**





# AM1064-1 - Amplifier

# DC to 8 GHz Gain Block



#### **Table of Contents**

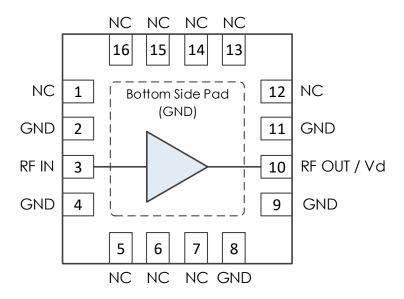
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# **Revision History**

Date	<b>Revision Number</b>	Notes
April 24, 2017	8	Features Updated
July 18, 2018	9	Updated to new datasheet format. More comprehensive part data added.
November 27, 2018	10	Thermal Resistance Corrected
March 28, 2019	11	Power vs. VDD Comparison Added
April 30, 2019	12	AM1064-1 and AM1064-2 Datasheets Split
June 6, 2019	12A	Component Compliance Information Updated
July 11, 2019	13	Part Ordering Information Added. New RF Shielded Module Available.
November 26, 2019	13A	Updated Description to include shielded module packaging
March 27, 2020	14	Updated package information. Updated module drawing showing input and output locations.
November 10, 2020	15	Package and module information moved to main product page. IP2 data added.



# **Pin Layout and Definitions**



Pin Number	Pin Name	Pin Function
1	NC	Do Not Connect*
2	GND	Ground - Common
3	RF In	RF Input – 50 Ohms – DC Coupled. External DC Blocking Capacitor Required
4	GND	Ground - Common
5-7	NC	Do Not Connect*
8,9	GND	Ground - Common
10	RF Out / Vd	RF Output and DC Power Input – 50 Ohms – DC Coupled. External DC Blocking Capacitor Required
11	GND	Ground - Common
12-16	NC	Do Not Connect*
Case GND	GND	Ground - Common

<sup>\*</sup>NC pins may be grounded or left open



# Pin Layout and Definitions (Continued)

# **Specifications**

#### **Absolute Maximum Ratings**

	Minimum	Maximum
Supply Voltage	-0.3 V	+8.0 V
RF Input Power		+20 dBm
Operating Junction Temperature	-40 C	+150 C
Storage Temperature Range	-50 C	+150 C

**Note:** Any device operation beyond the Absolute Maximum Ratings may result in permanent damage to the device. The values listed in this table are extremes and do not imply functional operation of the device at these or any other conditions beyond what is listed under Recommended Operating Conditions. Any part subjected to conditions outside of what is recommended for an extended amount of time may suffer from reliability concerns.

#### **Handling Information**

	Minimum	Maximum
Storage Temperature Range (Recommended)	-50 C	+125 C
Moisture Sensitivity Level	MSL 3	



Atlanta Micro products are electrostatic sensitive. Follow safe handling practices to avoid damage

#### **Recommended Operating Conditions**

	Minimum	Typical	Maximum
Supply Voltage	+3.0 V		+5.2 V
Operating Case Temperature	-40 C		+85 C
Operating Junction Temperature	-40 C		+125 C

#### **Thermal Information**

	Thermal Resistance (°C / W)
Junction to Case Thermal Resistance (θ <sub>JC</sub> )	88

# AM1064-1 - Amplifier



# DC to 8 GHz Gain Block

#### **DC Electrical Characteristics**

(T = 25 °C unless otherwise specified)

Parameter	<b>Testing Conditions</b>	Minimum	Typical	Maximum
DC Supply Voltage		+3.3 V	+4.7 V	+5.0 V
DC Supply Current	Vd = 4.7 V		73 mA	
	Vd = 3.1 V		36 mA	
Power Dissipated	Vd = 4.7 V		0.34 W	
	Vd = 3.1 V		0.11 W	

#### **RF Performance**

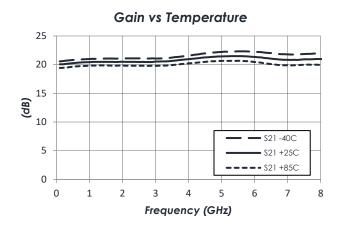
(T = 25 °C unless otherwise specified)

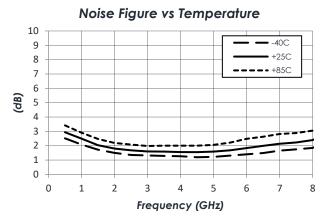
Parameter	<b>Testing Conditions</b>	Minimum	Typical	Maximum
Frequency Range		DC		8 GHz
Gain	Vd = 4.7 V		21 dB	
Return Loss	Vd = 4.7 V		12 dB	
Output IP3			+32.0 dBm	
Output P1dB			+18.0 dBm	
Noise Figure			2.0 dB	

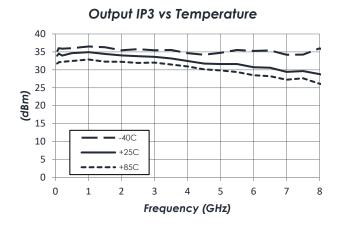


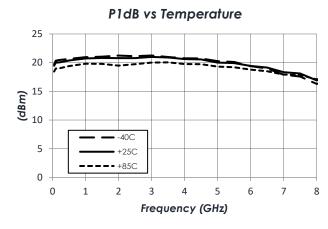
#### **Typical Performance**

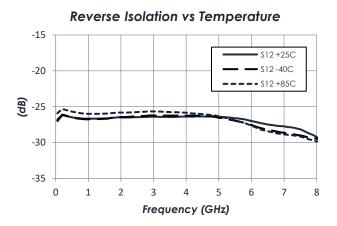
(Vd = +4.7 V, Id = 73 mA)









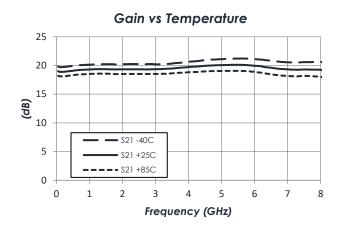


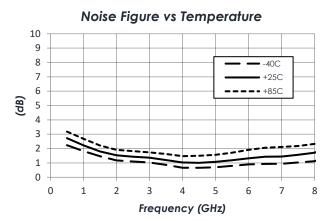
# ATLANTA — micro

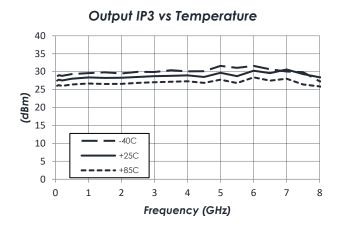
#### DC to 8 GHz Gain Block

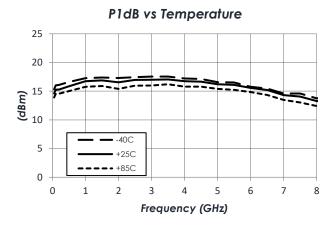
#### Typical Performance (continued)

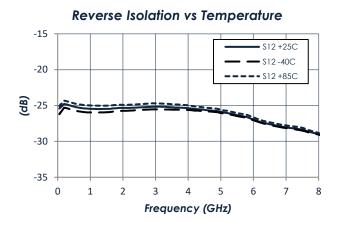
(Vd = +3.1 V, Id = 36 mA)







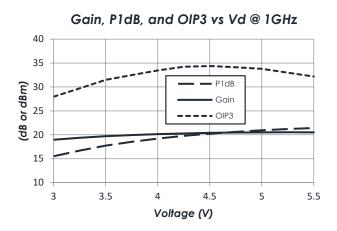


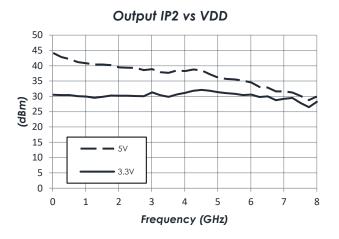


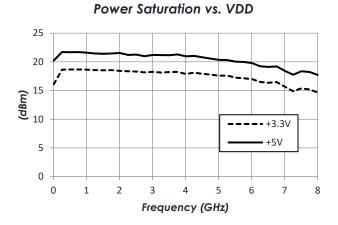


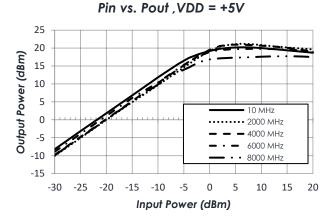
#### Typical Performance (continued)

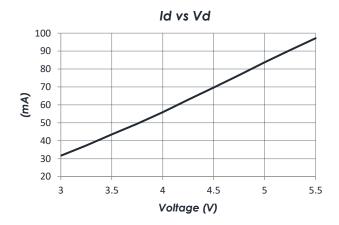
(T = 25 °C unless otherwise specified)





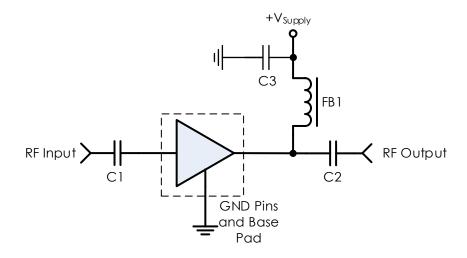








# **Typical Application**



#### Recommended Component List (or equivalent):

Part	Value	Part Number	Manufacturer
C1, C2	0.1µF	0402BB104KW160	Passives Plus
C3	0.1µF	GRM155R71C104KA88	Murata
FB1	-	MMZ1005A222E	TDK

#### Notes:

- 1. NC pins mays be grounded or left open
- 2. RF blocking capacitors should be high performance, low-loss, broadband capacitors for optimum performance



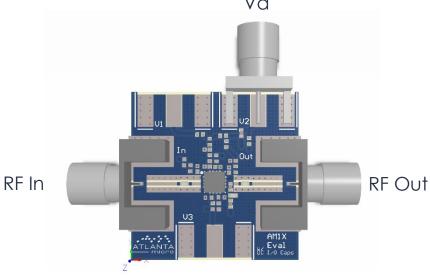
# **Part Ordering Details**

Description	Part Number
3mm 16 Lead QFN	AM1064-1
1.3mm x 2mm 6 Lead DFN (separate datasheet)	AM1064-2
AM1064-1 Evaluation Board	AM1064-1 Eval
AM1064-2 Evaluation Board	AM1064-2 Eval
AM1064-1 in 0.95" x 1.13" x 0.6" RF-Shielded Module with	AM1064-M
Integrated Bias Tee and Field Replaceable SMA Connectors	

# **Related Parts**

Part Number				Description
AM1064-2	DC	to	8 GHz	Miniature Gain Block
AM1016B	20 MHz	to	6 GHz	+3.3V Gain Block
AM1018C	20 MHz	to	6 GHz	+5.0V Gain Block
AM1025B	20 MHz	to	3 GHz	+8.0V Gain Block (High P1dB)
AM1031C	20 MHz	to	8 GHz	+3.3V Gain Block
AM1063-1	DC	to	10 GHz	Gain Block
AM1063-2	DC	to	10 GHz	Miniature Gain Block
AM1065	DC	to	8 GHz	Bypassable Gain Block
AM1073	DC	to	8 GHz	Bidirectional / Bypassable Gain Block

# Evaluation PC Board



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#### **Component Compliance Information**

**RoHS:** Atlanta Micro, Inc. hereby certifies that all products comply with the EC Directive 2011/65/EC on the Restriction of Hazardous Substances, commonly known as EU-RoHS 6 and 10. All products supplied by Atlanta Micro shall be compliant with the European Directive 2011/65/EC based on the following substance list.

Substance List	Allowable Maximum Concentration
Lead (Pb)	<1000 PPM (0.1% by weight)
Mercury (Hg)	<1000 PPM (0.1% by weight)
Cadmium (Cd)	<75 PPM (0.0075% by weight)
Hexavalent Chromium (CrVI)	<1000 PPM (0.1% by weight)
Polybrominated Biphenyls (PBB)	<1000 PPM (0.1% by weight)
Polybrominated Diphenyl ethers (PBDE)	<1000 PPM (0.1% by weight)
Decabromodiphenyl Deca BDE	<1000 PPM (0.1% by weight)
Bis (2-ethylheyl) Phthalate (DEHP)	<1000 PPM (0.1% by weight)
Butyl Benzyl Phthalate (BBP)	<1000 PPM (0.1% by weight)
Dibutyl Phthalate (DBP)	<1000 PPM (0.1% by weight)
Diisobutyl Phthalate (DIBP)	<1000 PPM (0.1% by weight)

**REACH:** Atlanta Micro, Inc. neither uses nor intentionally adds any of the substances considered to be a Substance of Very High Concern (SVHC) as defined by the EU Regulation (EC) No. 1907-2006 on Registration, Evaluation, Authorization, and Restriction of Chemicals (REACH).

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Atlanta Micro takes its responsibility as a global partner seriously and will use due diligence within our supply chain to ensure all standards are met to the best of our knowledge.